

Features

- ◆ 1M x 4 advanced high-speed CMOS Static RAM
- ◆ JEDEC Center Power / GND pinout for reduced noise
- ◆ Equal access and cycle times
— Commercial and Industrial: 10/12/15ns
- ◆ Single 3.3V power supply
- ◆ One Chip Select plus one Output Enable pin
- ◆ Bidirectional data inputs and outputs directly LVTTTL-compatible
- ◆ Low power consumption via chip deselect
- ◆ Available in 32-pin, 400 mil plastic SOJ package
- ◆ Green parts available, see ordering information

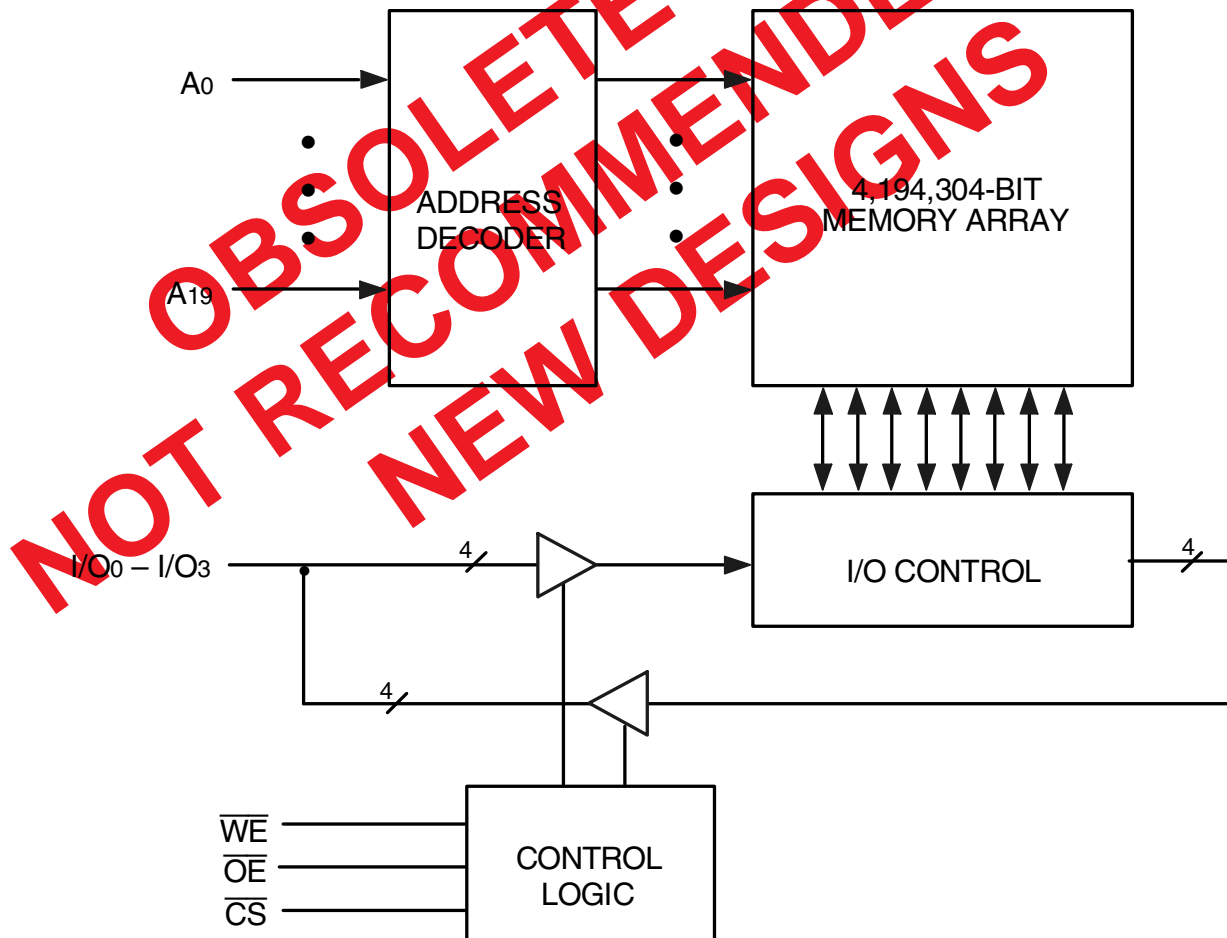
Description

The IDT71V428 is a 4,194,304-bit high-speed Static RAM organized as 1M x 4. It is fabricated using IDT's high-performance, high-reliability CMOS technology. This state-of-the-art technology, combined with innovative circuit design techniques, provides a cost-effective solution for high-speed memory needs.

The IDT71V428 has an output enable pin which operates as fast as 5ns, with address access times as fast as 10ns. All bidirectional inputs and outputs of the IDT71V428 are LVTTTL-compatible and operation is from a single 3.3V supply. Fully static asynchronous circuitry is used, requiring no clocks or refresh for operation.

The IDT71V428 is packaged in a 32-pin, 400 mil Plastic SOJ.

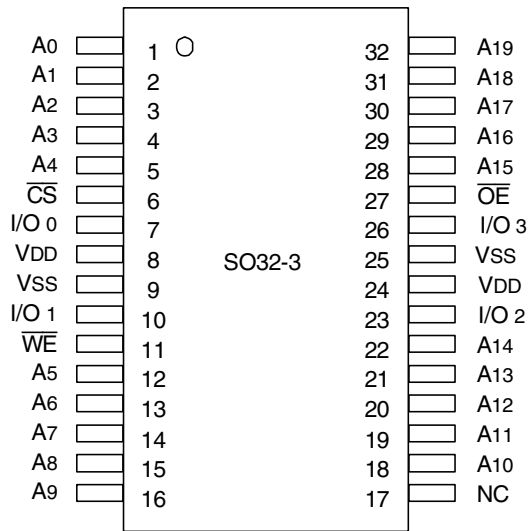
Functional Block Diagram



3623 drw 01

JULY 2014

Pin Configuration



SOJ Top View

3623 drw 02

Pin Description

A0 - A19	Address Inputs	Input
\overline{CS}	Chip Select	Input
\overline{WE}	Write Enable	Input
\overline{OE}	Output Enable	Input
I/O ₀ - I/O ₃	Data Input/Output	I/O
VDD	3.3V Power	Power
VSS	Ground	Gnd

3623 tbl 02

Capacitance

(T_A = +25°C, f = 1.0MHz, SOJ package)

Symbol	Parameter ⁽¹⁾	Conditions	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 3dV	7	pF
C _{I/O}	I/O Capacitance	V _{OUT} = 3dV	8	pF

3623 tbl 03

NOTE:

- This parameter is guaranteed by device characterization, but not production tested.

Truth Table^(1,2)

\overline{CS}	\overline{OE}	\overline{WE}	I/O	Function
L	L	H	DATA _{OUT}	Read Data
L	X	L	DATA _{IN}	Write Data
L	H	H	High-Z	Output Disabled
H	X	X	High-Z	Deselected - Standby (I _{SB})
V _{HC} ⁽³⁾	X	X	High-Z	Deselected - Standby (I _{SB1})

3623 tbl 01

NOTES:

- H = V_{IH}, L = V_{IL}, x = Don't care.
- V_{LC} = 0.2V, V_{HC} = V_{CC} - 0.2V.
- Other inputs ≥ V_{HC} or ≤ V_{LC}.

Absolute Maximum Ratings⁽¹⁾

Symbol	Rating	Value	Unit
V _{DD}	Supply Voltage Relative to V _{SS}	-0.5 to +4.6	V
V _{IN} , V _{OUT}	Terminal Voltage Relative to V _{SS}	-0.5 to V _{DD} +0.5	V
T _{BIAS}	Temperature Under Bias	-55 to +125	°C
T _{STG}	Storage Temperature	-55 to +125	°C
P _T	Power Dissipation	1	W
I _{OUT}	DC Output Current	50	mA

3623 tbl 04

NOTE:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Temperature and Supply Voltage

Grade	Temperature	V _{SS}	V _{DD}
Commercial	0°C to +70°C	0V	See Below
Industrial	-40°C to +85°C	0V	See Below

3623 tbl 05

Recommended DC Operating Conditions

Symbol	Parameter	Min.	Typ.	Max.	Unit
V _{DD}	Supply Voltage	3.0	3.3	3.6	V
V _{SS}	Ground	0	0	0	V
V _{IH}	Input High Voltage	2.0	—	V _{DD} +0.3 ⁽¹⁾	V
V _{IL}	Input Low Voltage	-0.3 ⁽²⁾	—	0.8	V

3623 tbl 06

NOTES:

- V_{IH} (max.) = V_{DD}+2V for pulse width less than 5ns, once per cycle.
- V_{IL} (min.) = -2V for pulse width less than 5ns, once per cycle.

DC Electrical Characteristics

(V_{DD} = Min. to Max., Commercial and Industrial Temperature Ranges)

Symbol	Parameter	Test Condition	IDT71V428		Unit
			Min.	Max.	
I _L	Input Leakage Current	V _{DD} = Max., V _{IN} = V _{SS} to V _{DD}	—	5	μA
I _{LO}	Output Leakage Current	V _{DD} = Max., \overline{CS} = V _{IH} , V _{OUT} = V _{SS} to V _{DD}	—	5	μA
V _{OL}	Output Low Voltage	I _{OL} = 8mA, V _{DD} = Min.	—	0.4	V
V _{OH}	Output High Voltage	I _{OH} = -4mA, V _{DD} = Min.	2.4	—	V

3623 tbl 07

DC Electrical Characteristics^(1,2,3)

(V_{DD} = Min. to Max., V_{LC} = 0.2V, V_{HC} = V_{DD} - 0.2V)

Symbol	Parameter		71V428S/L10		71V428S/L12		71V428S/L15		Unit
			Com'l.	Ind. ⁽⁵⁾	Com'l.	Ind.	Com'l.	Ind.	
I _{CC}	Dynamic Operating Current $\overline{CS} \leq V_{LC}$, Outputs Open, V _{DD} = Max., f = f _{MAX} ⁽⁴⁾	S	150	150	140	140	130	130	mA
		L	140	—	130	130	120	120	mA
I _{SB}	Dynamic Standby Power Supply Current $\overline{CS} \geq V_{HC}$, Outputs Open, V _{DD} = Max., f = f _{MAX} ⁽⁴⁾	S	60	60	50	50	40	40	mA
		L	40	—	35	35	30	30	mA
I _{SB1}	Full Standby Power Supply Current (static) $\overline{CS} \geq V_{HC}$, Outputs Open, V _{DD} = Max., f = 0 ⁽⁴⁾	S	20	20	20	20	20	20	mA
		L	10	—	10	10	10	10	mA

3623 tbl 08

NOTES:

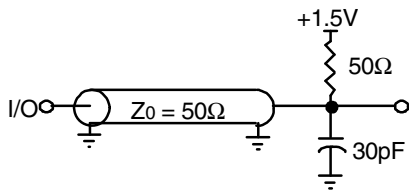
- All values are maximum guaranteed values.
- All inputs switch between 0.2V (Low) and V_{DD} - 0.2V (High).
- Power specifications are preliminary.
- f_{MAX} = 1/trc (all address inputs are cycling at f_{MAX}); f = 0 means no address input lines are changing.
- Standard power 10ns (S10) speed grade only.

AC Test Conditions

Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	1.5ns
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
AC Test Load	See Figure 1, 2 and 3

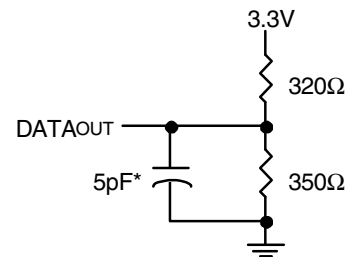
3623 tbl 09

AC Test Loads



3623 drw 03

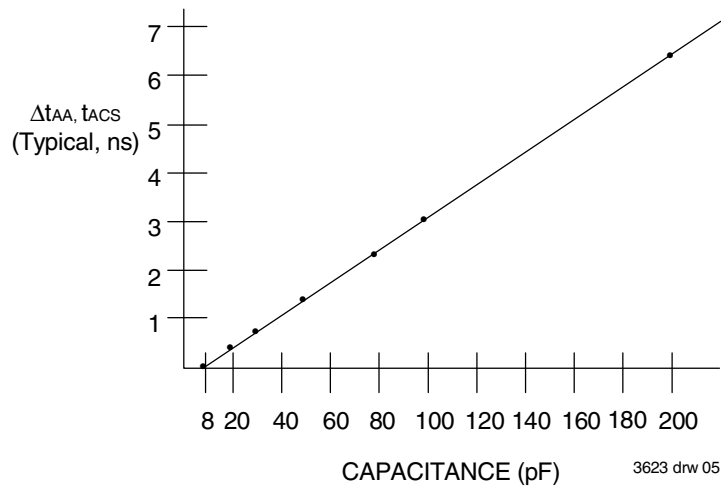
Figure 1. AC Test Load



3623 drw 04

* Including jig and scope capacitance.

Figure 2. AC Test Load
(for tCLZ, tOLZ, tCHZ, tOHZ, tOW, and tWHZ)



3623 drw 05

Figure 3. Output Capacitive Derating

AC Electrical Characteristics (V_{DD} = 3.3V ± 10%, Commercial and Industrial Temperature Ranges)

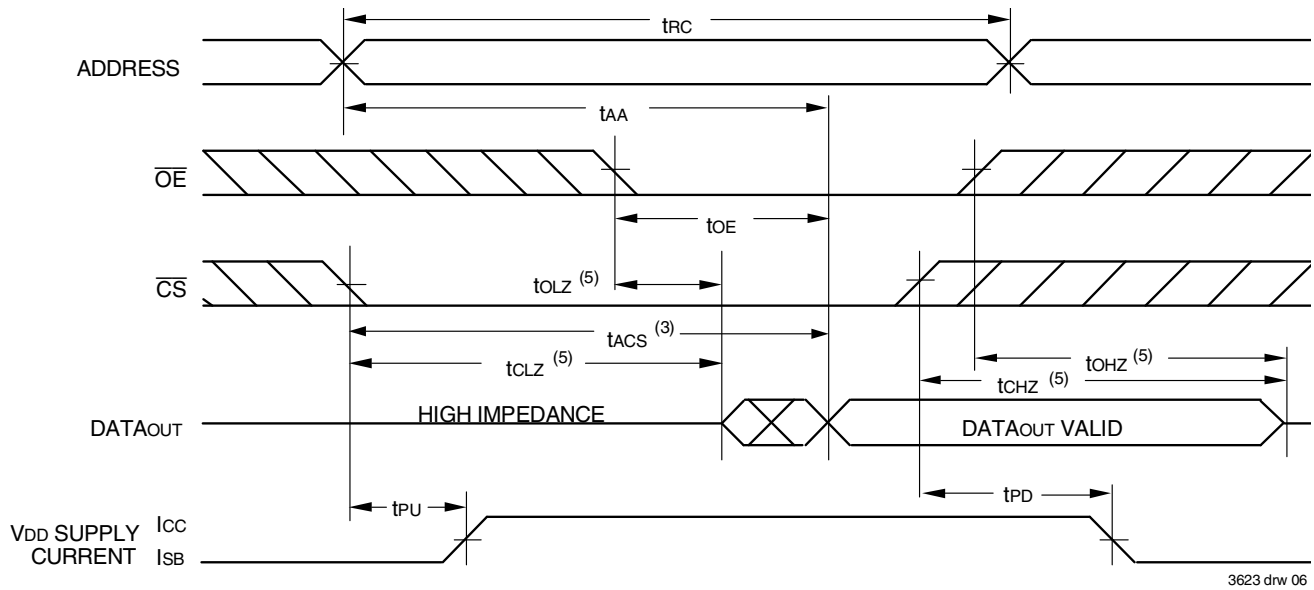
Symbol	Parameter	71V428S/L10 ⁽²⁾		71V428S/L12		71V428S/L15		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
READ CYCLE								
t _{RC}	Read Cycle Time	10	—	12	—	15	—	ns
t _{AA}	Address Access Time	—	10	—	12	—	15	ns
t _{ACS}	Chip Select Access Time	—	10	—	12	—	15	ns
t _{CLZ} ⁽¹⁾	Chip Select to Output in Low-Z	4	—	4	—	4	—	ns
t _{CHZ} ⁽¹⁾	Chip Deselect to Output in High-Z	—	5	—	6	—	7	ns
t _{OE}	Output Enable to Output Valid	—	5	—	6	—	7	ns
t _{OLZ} ⁽¹⁾	Output Enable to Output in Low-Z	0	—	0	—	0	—	ns
t _{OHZ} ⁽¹⁾	Output Disable to Output in High-Z	—	5	—	6	—	7	ns
t _{OH}	Output Hold from Address Change	4	—	4	—	4	—	ns
t _{PU} ⁽¹⁾	Chip Select to Power Up Time	0	—	0	—	0	—	ns
t _{PD} ⁽¹⁾	Chip Deselect to Power Down Time	—	10	—	12	—	15	ns
WRITE CYCLE								
t _{WC}	Write Cycle Time	10	—	12	—	15	—	ns
t _{AW}	Address Valid to End of Write	8	—	8	—	10	—	ns
t _{CW}	Chip Select to End of Write	8	—	8	—	10	—	ns
t _{AS}	Address Set-up Time	0	—	0	—	0	—	ns
t _{WP}	Write Pulse Width	8	—	8	—	10	—	ns
t _{WR}	Write Recovery Time	0	—	0	—	0	—	ns
t _{DW}	Data Valid to End of Write	6	—	6	—	7	—	ns
t _{DH}	Data Hold Time	0	—	0	—	0	—	ns
t _{OW} ⁽¹⁾	Output Active from End of Write	3	—	3	—	3	—	ns
t _{WHZ} ⁽¹⁾	Write Enable to Output in High-Z	—	6	—	7	—	7	ns

3623 tbl 10

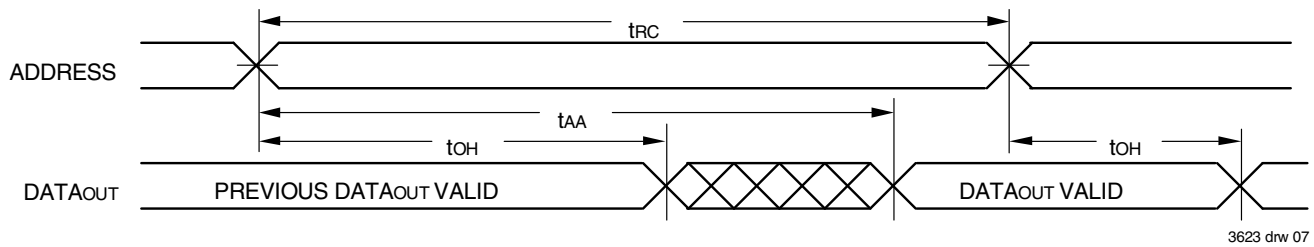
NOTES:

1. This parameter guaranteed with the AC load (Figure 2) by device characterization, but is not production tested.
2. 0°C to +70°C temperature range only for low power 10ns (L10) speed grade.

Timing Waveform of Read Cycle No. 1⁽¹⁾



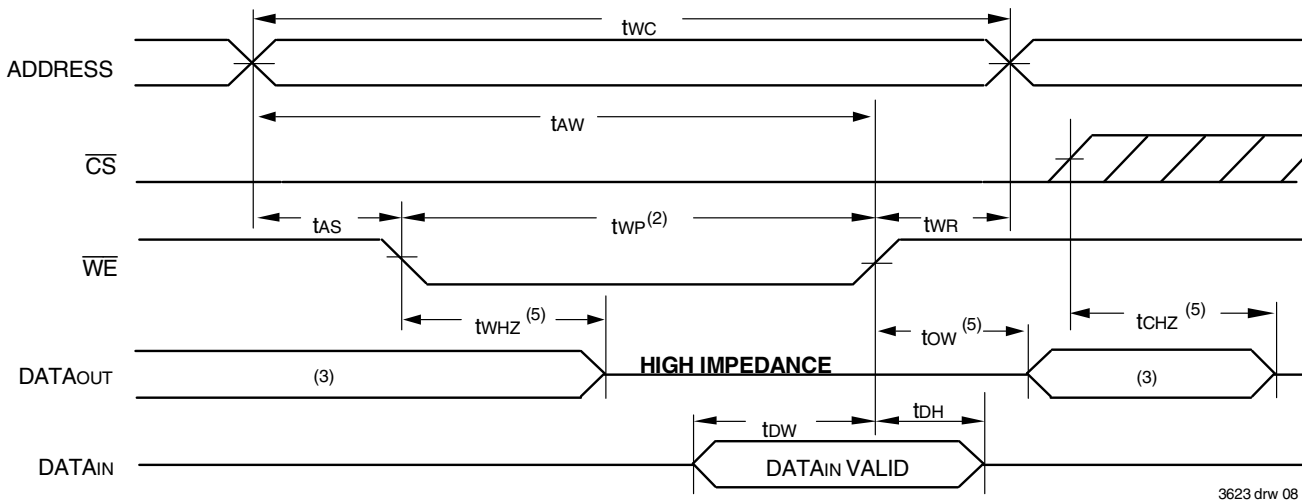
Timing Waveform of Read Cycle No. 2^(1,2,4)



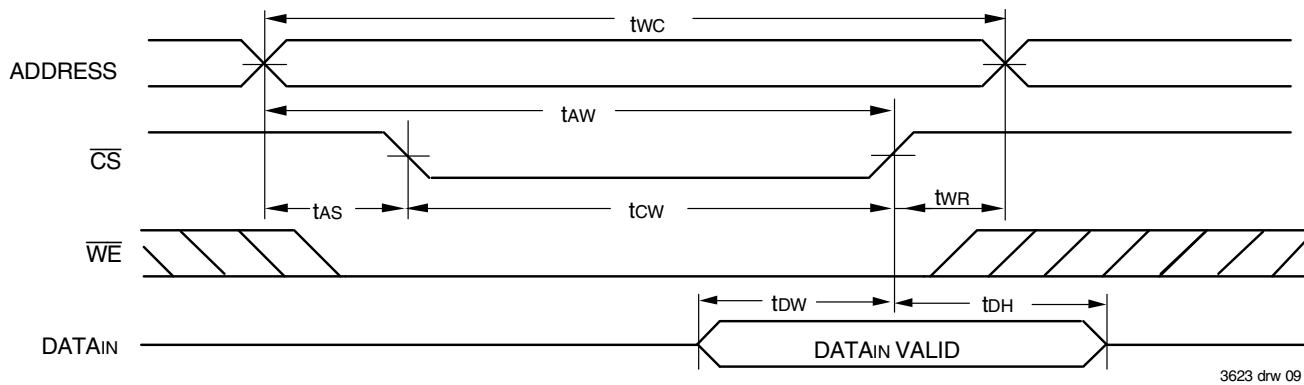
NOTES:

1. \overline{WE} is HIGH for Read Cycle.
2. Device is continuously selected, \overline{CS} is LOW.
3. Address must be valid prior to or coincident with the later of \overline{CS} transition LOW; otherwise t_{AA} is the limiting parameter.
4. \overline{OE} is LOW.
5. Transition is measured $\pm 200\text{mV}$ from steady state.

Timing Waveform of Write Cycle No.1 (\overline{WE} Controlled Timing)^(1,2,4)



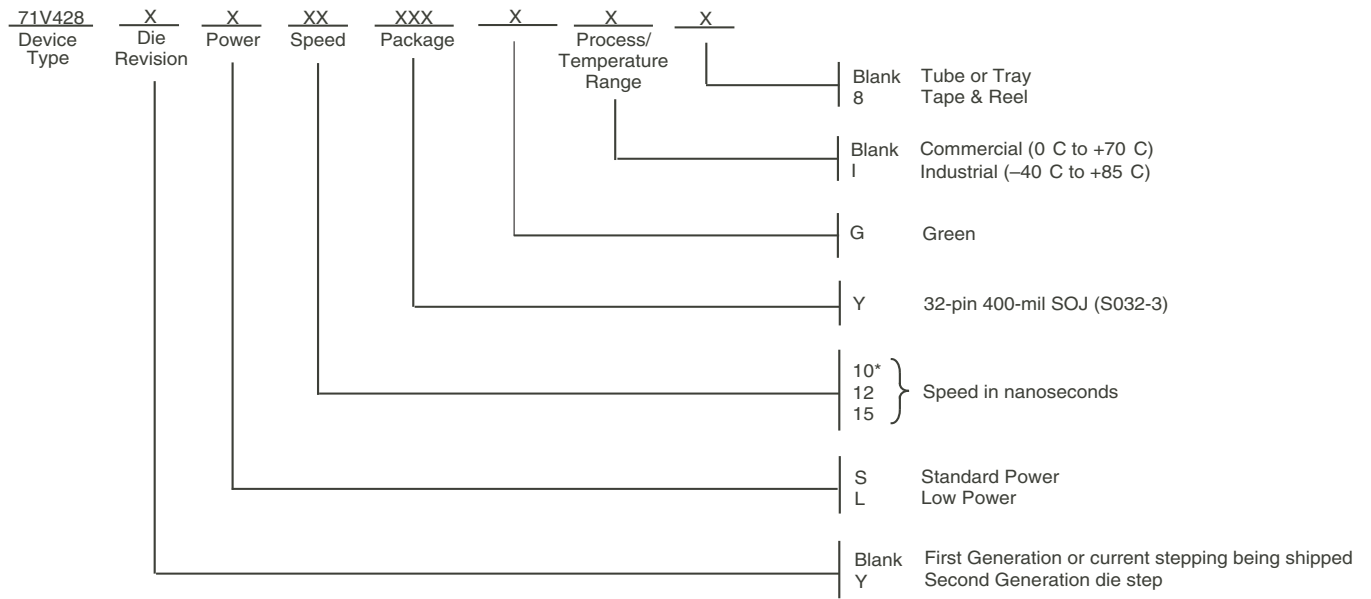
Timing Waveform of Write Cycle No.2 (\overline{CS} Controlled Timing)^(1,4)



NOTES:

1. A write occurs during the overlap of a LOW \overline{CS} and a LOW \overline{WE} .
2. \overline{OE} is continuously HIGH. If during a \overline{WE} controlled write cycle \overline{OE} is LOW, t_{WP} must be greater than or equal to $t_{WHZ} + t_{OW}$ to allow the I/O drivers to turn off and data to be placed on the bus for the required t_{OW} . If \overline{OE} is HIGH during a \overline{WE} controlled write cycle, this requirement does not apply and the minimum write pulse is as short as the specified t_{WP} .
3. During this period, I/O pins are in the output state, and input signals must not be applied.
4. If the \overline{CS} LOW transition occurs simultaneously with or after the \overline{WE} LOW transition, the outputs remain in a high-impedance state.
5. Transition is measured $\pm 200\text{mV}$ from steady state.

Ordering Information



* Commercial only for low power (L10) speed grade.

3623 drw 10

Datasheet Document History

8/31/99		Updated to new format
	Pg. 2	Added footnote for VHC in Truth Table
	Pg. 4	Added footnote on jig and scope capacitance in Figure 2
	Pg. 7	Revised footnote on Write Cycle No. 1 diagram
	Pg. 9	Added Datasheet Document History
9/29/99	Pg. 1-9	Added Industrial temperature range offerings
11/26/02	Pg. 8	Updated ordering information for die revision
07/31/03	Pg. 8	Updated note, L10 speed grade commercial temperature only and updated die stepping from YF to Y.
09/30/04	Pg. 8	Added "Restricted hazardous substance device" to ordering information.
07/18/14	Pg. 1	Added green availability to Features
07/18/14	Pg. 8	Changed Restricted hazardous substance device indicator to Green in the ordering information
07/18/14	Pg. 8	Added T & R indicator to ordering Information
01/01/07		PDN-SR-0607. See IDT.com for PDN specifics

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